

Recent Papers by IBM Authors

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• Papers are listed alphabetically by name of journal.

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How to Increase Computer Size without Making the Machine Bigger, S. C. Kiely (SDD Kingston, N.Y.), *Electronic Design* 21, No. 11, 148-150 (May 24, 1973).

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Financial Modeling on Small Systems, R. J. Gordon (DPD Branch Office, Worcester, Ma.), *IBM Systems Journal* 12, No. 2, 161-171 (1973).

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